TOSHIBA Field Effect Transistor Silicon P/N Channel MOS Type(π-MOSVI)

SSM6L16FE

High Speed Switching Applications

Analog Switch Applications

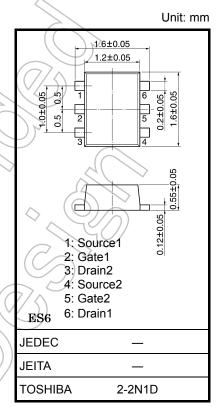
- Small package
- Low on-resistance Q1: $R_{DS(ON)} = 4 \Omega (max) (@V_{GS} = 2.5 V)$ Q2: $R_{DS(ON)} = 12 \Omega (max) (@V_{GS} = -2.5 V)$

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V _{DSS}	20	V
Gate-Source voltage		V _{GSS}	±10	V
Drain current	DC	۱ _D	100	
	Pulse	I _{DP}	200	

Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V _{DSS}	-20	X
Gate-Source voltage		V _{GSS}) ⊉10	X
Drain current	DC	ID	-100	mA
	Pulse		-200	



Weight: 3 mg (typ.)

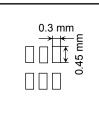
Absolute Maximum Ratings (Q1, Q2 Common) (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power dissipation	P _D (Note 1)	150	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

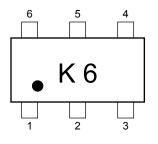
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating, mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 mm, Cu Pad: 0.135 mm² \times 6)

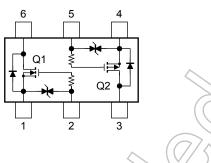


Start of commercial production 2002-03

Marking



Equivalent Circuit (top view)



Handling Precaution

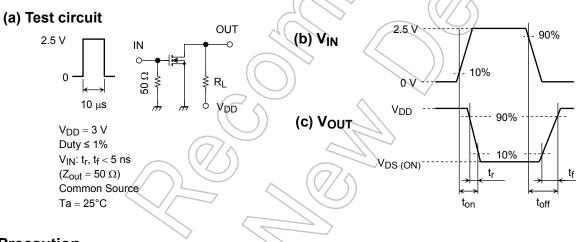
When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against static electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Q1 Electrical Characteristics (Ta = 25°C)

Charac	teristic	Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT
Gate leakage current		I _{GSS}	$V_{GS}=\pm 10~V,~V_{DS}=0$			±1	μA
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	20			V
Drain cut-off current		I _{DSS}	$V_{DS} = 20 V, V_{GS} = 0$	\nearrow		1	μA
Gate threshold voltage		V _{th}	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 0.1 \text{ mA}$	0.6		1.1	V
Forward transfer admittance		Y _{fs}	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 10 \text{ mA} \qquad (\text{Note2})$	40)}		mS
Drain-Source on-resistance		R _{DS} (ON)	$I_D = 10 \text{ mA}, V_{GS} = 4 \text{ V}$ (Note2)	77	1.5	3.0	Ω
			I _D = 10 mA, V _{GS} = 2.5 V (Note2)	\bigcirc	2.2	4.0	
			$I_D = 1 \text{ mA}, V_{GS} = 1.5 \text{ V}$ (Note2)	_	5.2	15	
Input capacitance		C _{iss}		⁷ —	9.3		pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$		4.5		pF
Output capacitance		C _{OSS}		_	9.8	\searrow	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 3 V, I_D = 10 mA,$	-6	70	> -	
	Turn-off time	t _{off}			125) —	ns

Note2: Pulse test

Switching Time Test Circuit



Precaution

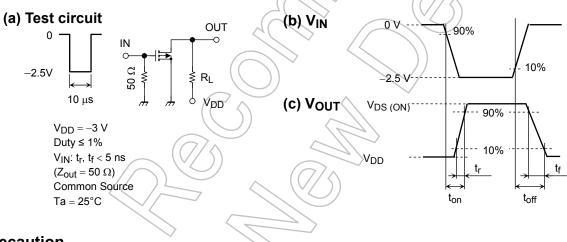
 $\begin{array}{l} V_{th} \mbox{ can be expressed as the voltage between the gate and source when the low operating current value is ID = 0.1 mA for this product. For normal switching operation, V_{GS} (_{on}) requires a higher voltage than V_{th} and V_{GS} (_{off}) requires a lower voltage than V_{th}. (The relationship can be established as follows: V_{GS} (_{off}) < V_{th} < V_{GS} (_{on}).) \\ Be sure to take this into consideration when using the device. \end{array}$

Q2 Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT
Gate leakage current		I _{GSS}	$V_{GS}=\pm 10~V,~V_{DS}=0$		—	±1	μA
Drain-Source breakdown voltage V (V (BR) DSS	$I_D = -0.1 \text{ mA}, V_{GS} = 0$	-20	_	_	V
Drain cut-off current		I _{DSS}	$V_{DS} = -20 V, V_{GS} = 0$	X	—	-1	μA
Gate threshold voltage		V _{th}	$V_{DS} = -3 \text{ V}, \text{ I}_{D} = -0.1 \text{ mA}$	-0.6		-1.1	V
Forward transfer admittance		Y _{fs}	$V_{DS} = -3 V, I_D = -10 mA$ (Note3)	25	-((_	mS
Drain-Source on-resistance		R _{DS (ON)}	$I_D = -10 \text{ mA}, V_{GS} = -4 \text{ V}$ (Note3)	K	6	8	Ω
			I _D = -10 mA, V _{GS} = -2.5 V (Note3))	8	12	
			$I_D = -1 \text{ mA}, V_{GS} = -1.5 \text{ V}$ (Note3)		18	45	
Input capacitance		C _{iss}		<u> </u>	11	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = -3 V, V_{GS} = 0, f = 1 MHz$		3.7		pF
Output capacitance		C _{oss}		_	(10	\searrow	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = -3 V, I_D = -10 mA,$	-6	130	> -	
	Turn-off time	t _{off}	$V_{GS} = 0$ to -2.5 V		190) —	ns

Note3: Pulse test

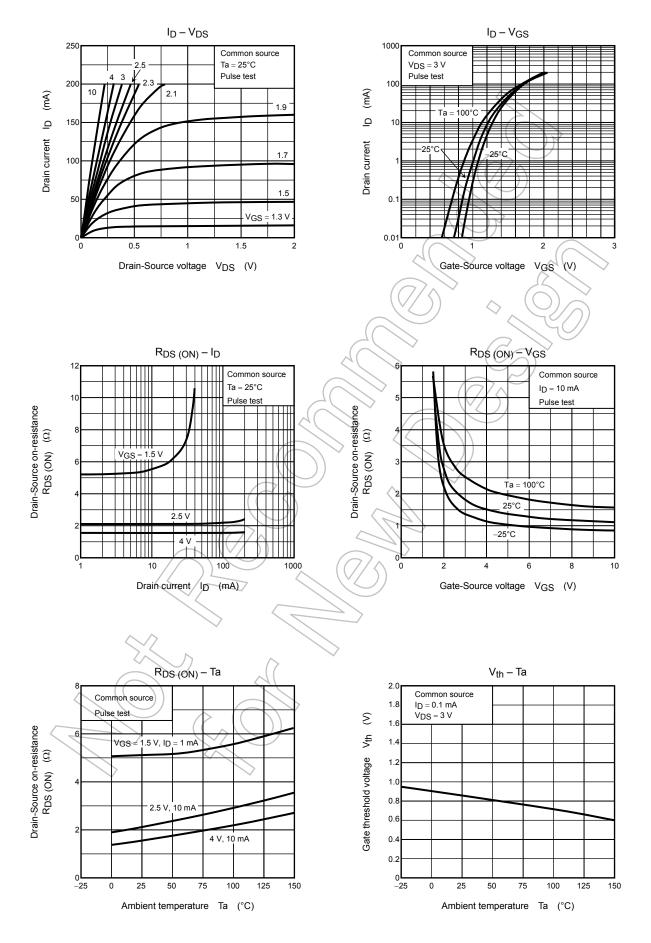
Switching Time Test Circuit



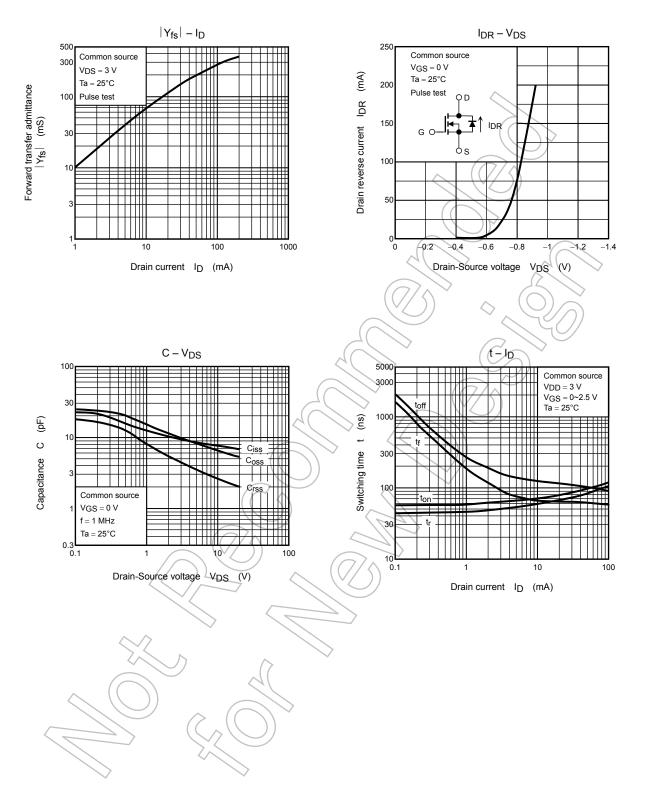
Precaution

 $\begin{array}{l} V_{th} \mbox{ can be expressed as the voltage between the gate and source when the low operating current value is ID = -0.1 mA for this product. For normal switching operation, VGS (on) requires a higher voltage than V_{th} and VGS (off) requires a lower voltage than V_{th}. (The relationship can be established as follows: VGS (off) < V_{th} < V_{GS} (on).) \\ Be sure to take this into consideration when using the device. \end{array}$

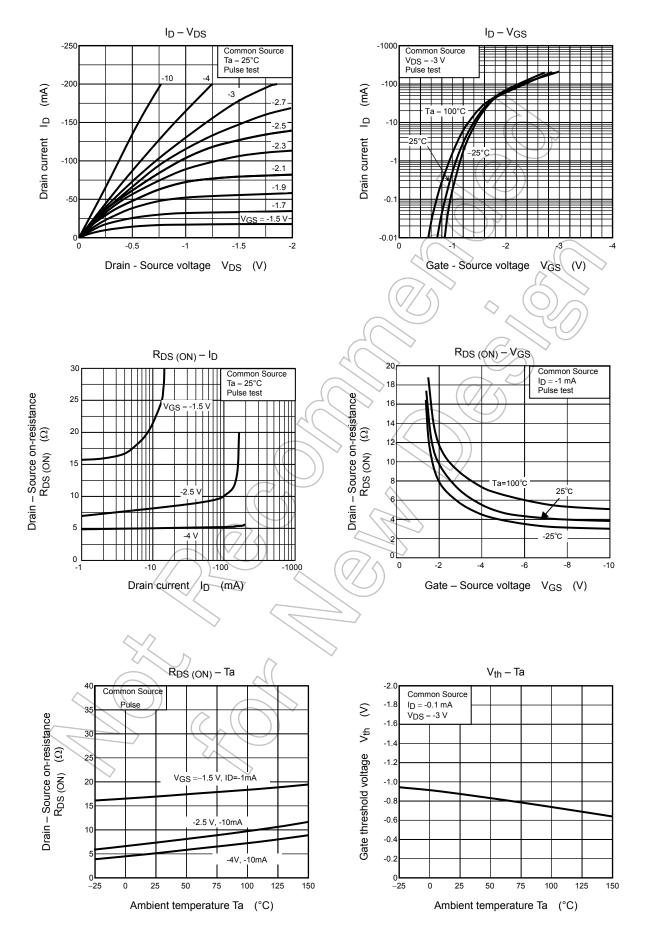
Q1 (N-ch MOSFET)



Q1 (N-ch MOSFET)

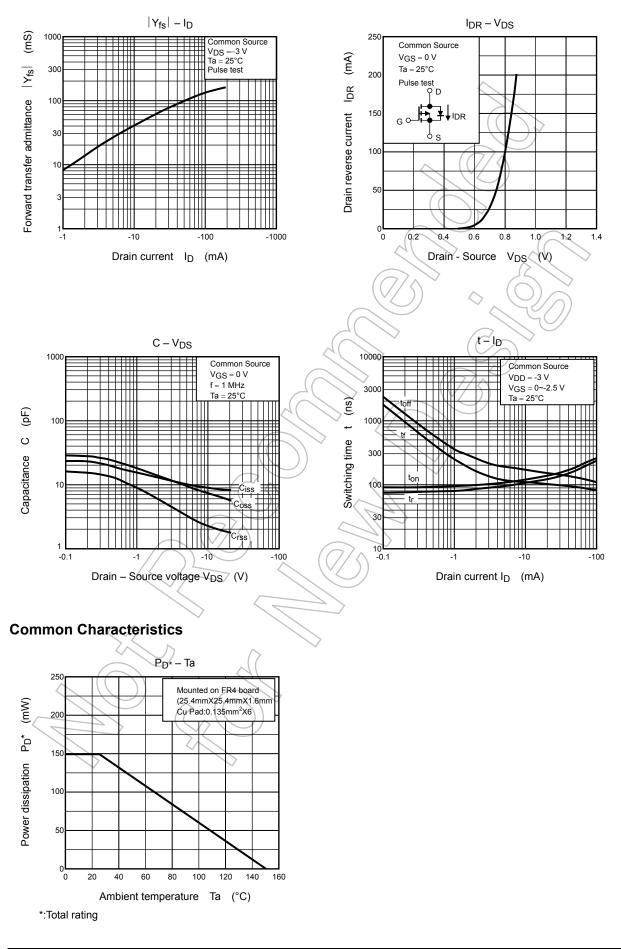


Q2 (P-ch MOSFET)



TOSHIBA

Q2 (P-ch MOSFET)



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